



SBAS156B - JULY 2002

Low-Power, Rail-to-Rail Output, 12-Bit Serial Input DIGITAL-TO-ANALOG CONVERTER

FEATURES

- microPOWER OPERATION: 135µA at 5V
- POWER-DOWN: 200nA at 5V, 50nA at 3V
- POWER SUPPLY: +2.7V to +5.5V
- TESTED MONOTONIC BY DESIGN
- POWER-ON RESET TO 0V
- THREE POWER-DOWN FUNCTIONS
- LOW POWER SERIAL INTERFACE WITH SCHMITT-TRIGGERED INPUTS
- ON-CHIP OUTPUT BUFFER AMPLIFIER, RAIL-TO-RAIL OPERATION
- SYNC INTERRUPT FACILITY
- SOT23-6 AND MSOP-8 PACKAGES

APPLICATIONS

- PORTABLE BATTERY-POWERED INSTRUMENTS
- DIGITAL GAIN AND OFFSET ADJUSTMENT
- PROGRAMMABLE VOLTAGE AND CURRENT SOURCES

DESCRIPTION

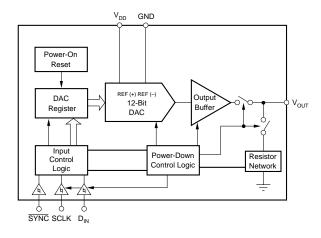
The DAC7512 is a low-power, single, 12-bit buffered voltage output Digital-to-Analog Converter (DAC). Its on-chip precision output amplifier allows rail-to-rail output swing to be achieved. The DAC7512 uses a versatile three-wire serial interface that operates at clock rates up to 30MHz and is compatible with standard SPI[™], QSPI[™], Microwire[™], and DSP interfaces.

The reference for the DAC7512 is derived from the power supply, resulting in the widest dynamic output range possible. The DAC7512 incorporates a power-on reset circuit that ensures that the DAC output powers up at 0V and remains there until a valid write takes place in the device. The DAC7512 contains a power-down feature, accessed over the serial interface, that can reduce the current consumption of the device to 50nA at 5V.

The low power consumption of this part in normal operation makes it ideally suited to portable battery-operated equipment. The power consumption is 0.7mW at 5V reducing to 1μ W in power-down mode.

The DAC7512 is available in a SOT23-6 package and an MSOP-8 package.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ABSOLUTE MAXIMUM RATINGS(1)

V _{DD} to GND0.3V to +6V
Digital Input Voltage to GND0.3V to +V _{DD} + 0.3V
V_{OUT} to GND0.3V to + V_{DD} + 0.3V
Operating Temperature Range40°C to +105°C
Storage Temperature Range65°C to +150°C
Junction Temperature Range (T _J max)+150°C
SOT23 Package:
Power Dissipation $(T_{J} \max - T_{A})/J_{A}$
_{JA} Thermal Impedance240°C/W
Lead Temperature, Soldering:
Vapor Phase (60s)+215°C
Infrared (15s)+220°C
MSOP Package:
Power Dissipation
_{JA} Thermal Impedance
JC Thermal Impedance
Lead Temperature, Soldering:
Vapor Phase (60s)+215°C
Infrared (15s) +220°C

NOTE: (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

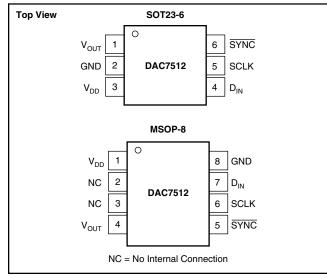
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

PRODUCT	MINIMUM RELATIVE ACCURACY (LSB)	DIFFERENTIAL NONLINEARITY (LSB)	PACKAGE-LEAD	PACKAGE DESIGNATOR ⁽¹⁾	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER ⁽¹⁾	TRANSPORT MEDIA, QUANTITY
DAC7512E " DAC7512N "	+8 = +8 =	±1 " ±1 "	MSOP-8 " SOT23-6	DGK " DBV "	-40°C to +105°C " -40°C to +105°C "	D12E " D12N "	DAC7512E/250 DAC7512E/2K5 DAC7512N/250 DAC7512N/3K	Tape and Reel, 250 Tape and Reel, 2500 Tape and Reel, 250 Tape and Reel, 3000

NOTES: (1) For the most current specifications and package information, refer to our web site at www.ti.com. (2) Models with a slash (/) are available only in Tape and Reel in the quantities indicated (e.g., /2K5 indicates 2500 devices per reel). Ordering 2500 pieces of "DAC7512E/2K5" will get a single 2500-piece Tape and Reel.

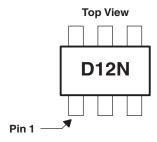
PIN CONFIGURATIONS

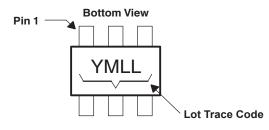


PIN DESCRIPTION (SOT23-6)

PIN	NAME	DESCRIPTION
1	V _{OUT}	Analog output voltage from DAC. The output ampli- fier has rail-to-rail operation.
2	GND	Ground reference point for all circuitry on the part.
3	V _{DD}	Power Supply Input, +2.7V to 5.5V.
4	D _{IN}	Serial Data Input. Data is clocked into the 16-bit input shift register on the falling edge of the serial clock input.
5	SCLK	Serial Clock Input. Data can be transferred at rates up to 30MHz.
6	SYNC	Level triggered control input (active LOW). This is the frame sychronization signal for the input data. When SYNC goes LOW, it enables the input shift register and data is transferred in on the falling edges of the following clocks. The DAC is updated following the 16th clock cycle unless SYNC is taken HIGH before this edge, in which case the rising edge of SYNC acts as an interrupt and the write sequence is ignored by the DAC7512.

DAC7512N LOT TRACE LOCATION









ELECTRICAL CHARACTERISTICS

 V_{DD} = +2.7V to +5.5V; R_L = 2ký to GND; C_L = 200pF to GND.

PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNITS	
STATIC PERFORMANCE (1)						
Resolution		12			Bits	
Relative Accuracy				±8	LSB	
Differential Nonlinearity	Tested Monotonic by Design			±1	LSB	
Zero Code Error	All Zeroes Loaded to DAC Register		+5	+20	mV	
Full-Scale Error	All Ones Loaded to DAC Register		-0.15	-1.25	% of FSR	
Gain Error	All ones Ebaded to BAO Register		0.10	±1.25	% of FSR	
Zero Code Error Drift			-20	11.20	μV/°C	
Gain Temperature Coefficient			-5		ppm of FSR/°C	
OUTPUT CHARACTERISTICS (2)						
Output Voltage Range		0		V _{DD}	V	
Output Voltage Settling Time	1/4 Scale to 3/4 Scale Change					
	(400 _H to C00 _H)		8	10	μs	
	$R_L = 2k\Omega; 0pF < C_L < 200pF$					
	$R_L = 2k\Omega; C_L = 500pF$		12		μs	
Slew Rate		1			V/µs	
					1,40	
Capacitive Load Stability	$R_{L} = x$		470		pF	
Capacitive Load Clability	$R_{\rm I} = 2k\Omega$		1000		pF	
Code Change Glitch Impulse	1LSB Change Around Major Carry		20		nV-s	
	TESB Change Around Major Carry		0.5		nV-s	
Digital Feedthrough					-	
DC Output Impedance			1		Ω	
Short-Circuit Current	$V_{DD} = +5V$		50		mA	
	$V_{DD} = +3V$		20		mA	
Power-Up Time	Coming Out of Power-Down Mode					
	$V_{DD} = +5V$		2.5		μs	
	Coming Out of Power-Down Mode					
	$V_{DD} = +3V$		5		μs	
LOGIC INPUTS (2)						
Input Current				±1	μA	
V _{IN} L, Input Low Voltage	$V_{DD} = +5V$			0.8	ľ V	
V _{IN} L, Input Low Voltage	$V_{\rm DD} = +3V$			0.6	v	
V _{IN} H, Input High Voltage	$V_{DD} = +5V$	2.4		0.0	v	
V _{IN} H, Input High Voltage	$V_{DD} = +3V$	2.1			v v	
Pin Capacitance	V _{DD} = +3V	2.1		3	pF	
					P1	
		0.7			v	
V _{DD}	DAC Active and Evoluting Los 4 Current	2.7		5.5	v	
I _{DD} (normal mode)	DAC Active and Excluding Load Current		105		l .	
$V_{DD} = +3.6V \text{ to } +5.5V$	$V_{IH} = V_{DD}$ and $V_{IL} = GND$		135	200	μΑ	
$V_{DD} = +2.7V \text{ to } +3.6V$	$V_{IH} = V_{DD}$ and $V_{IL} = GND$		115	160	μA	
I _{DD} (all power-down modes)						
$V_{DD} = +3.6V \text{ to } +5.5V$	$V_{IH} = V_{DD}$ and $V_{IL} = GND$		0.2	1	μA	
$V_{DD} = +2.7V \text{ to } +3.6V$	$V_{IH} = V_{DD}$ and $V_{IL} = GND$		0.05	1	μΑ	
POWER EFFICIENCY						
I _{OUT} /I _{DD}	$I_{LOAD} = 2mA. V_{DD} = +5V$		93		%	
TEMPERATURE RANGE						
Specified Performance		-40		+105	°C	

NOTES: (1) Linearity calculated using a reduced code range of 48 to 4047; output unloaded. (2) Guaranteed by design and characterization, not production tested.



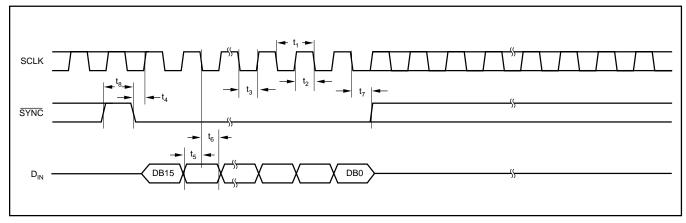
TIMING CHARACTERISTICS^(1, 2)

 V_{DD} = +2.7V to +5.5V; all specifications –40°C to +105°C, unless otherwise noted.

				DAC7512E, N		
PARAMETER	DESCRIPTION	CONDITIONS	MIN	ТҮР	МАХ	UNITS
t1 ⁽³⁾	SCLK Cycle Time					
	-	$V_{DD} = 2.7V$ to 3.6V	50			ns
		$V_{DD} = 3.6V$ to 5.5V	33			ns
t ₂	SCLK HIGH Time					
		V _{DD} = 2.7V to 3.6V	13			ns
		$V_{DD} = 3.6V$ to 5.5V	13			ns
t ₃	SCLK LOW Time					
		$V_{DD} = 2.7V$ to 3.6V	22.5			ns
		$V_{DD} = 3.6V$ to 5.5V	13			ns
t ₄	SYNC to SCLK Rising					
	Edge Setup Time					
		$V_{DD} = 2.7V$ to 3.6V	0			ns
		$V_{DD} = 3.6V$ to 5.5V	0			ns
t ₅	Data Setup Time					
		$V_{DD} = 2.7V$ to 3.6V	5			ns
		$V_{DD} = 3.6V$ to 5.5V	5			ns
t ₆	Data Hold Time					
		$V_{DD} = 2.7V$ to 3.6V	4.5			ns
		$V_{DD} = 3.6V$ to 5.5V	4.5			ns
t ₇	SCLK Falling Edge to					
	SYNC Rising Edge					
		$V_{DD} = 2.7V$ to 3.6V	0			ns
		$V_{DD} = 3.6V$ to 5.5V	0			ns
t ₈	Minimum SYNC HIGH Time					
		$V_{DD} = 2.7V$ to 3.6V	50			ns
		$V_{DD} = 3.6V$ to 5.5V	33			ns

NOTES: (1) All input signals are specified with $t_R = t_F = 5ns$ (10% to 90% of V_{DD}) and timed from a voltage level of ($V_{IL} + V_{IH}$)/2. (2) See Serial Write Operation timing diagram, below. (3) Maximum SCLK frequency is 30MHz at $V_{DD} = +3.6V$ to +5.5V and 20MHz at $V_{DD} = +2.7V$ to +3.6V.

SERIAL WRITE OPERATION

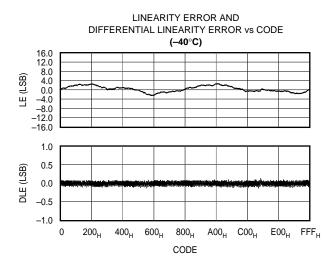


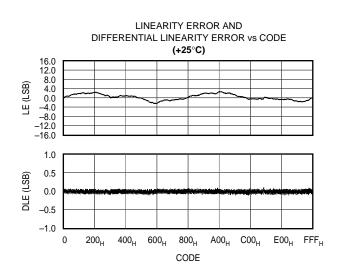


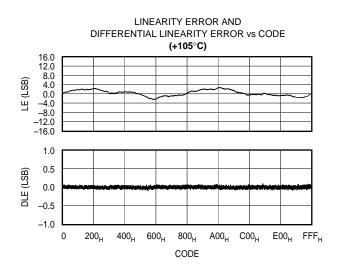


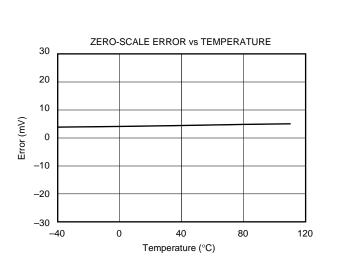
TYPICAL CHARACTERISTICS: $V_{DD} = +5V$

At T_{A} = +25°C, +V_{\text{DD}} = +5V, unless otherwise noted.

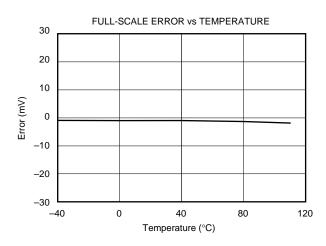








TYPICAL TOTAL UNADJUSTED ERROR $\begin{array}{c}
16\\
8\\
0\\
-8\\
-8\\
-16\\
0\\
200_{H} 400_{H} 600_{H} 800_{H} A00_{H} C00_{H} E00_{H} FFF_{H} \\
CODE
\end{array}$

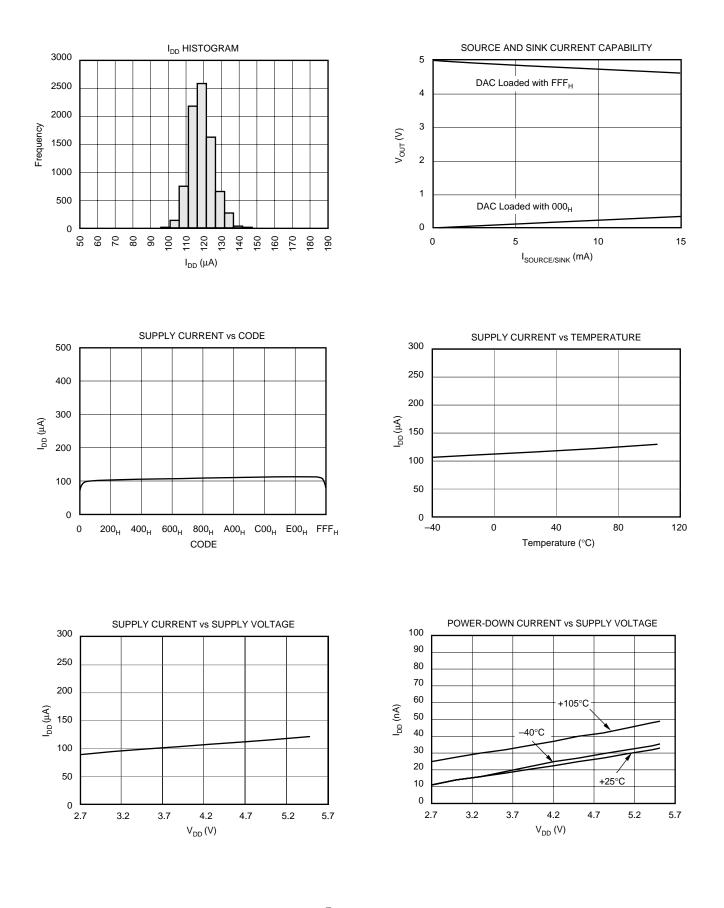






TYPICAL CHARACTERISTICS: $V_{DD} = +5V$ (Cont.)

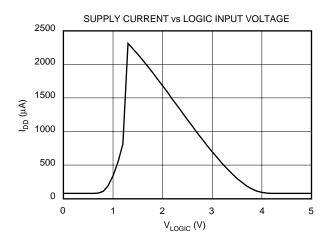
At T_A = +25°C, +V_{DD} = +5V, unless otherwise noted.

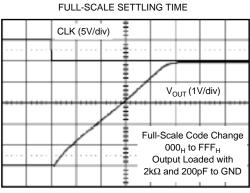




TYPICAL CHARACTERISTICS: $V_{DD} = +5V$ (Cont.)

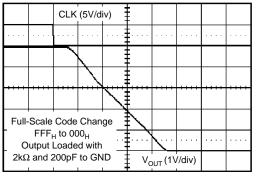
At T_A = +25°C, +V_{DD} = +5V, unless otherwise noted.



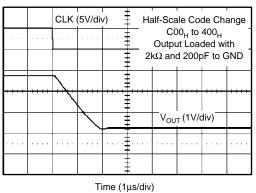


Time (1µs/div)

FULL-SCALE SETTLING TIME

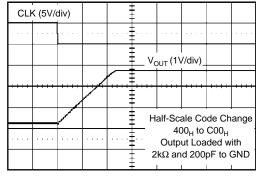


Time (1µs/div)



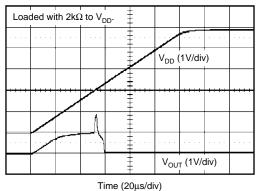
HALF-SCALE SETTLING TIME

HALF-SCALE SETTLING TIME



Time (1µs/div)

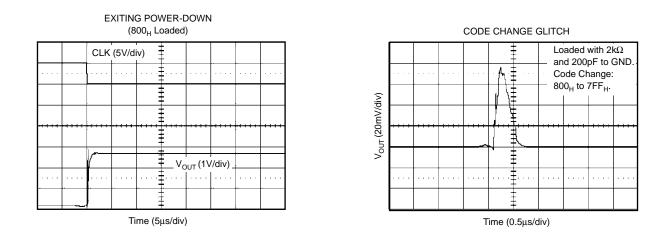
POWER-ON RESET TO 0V





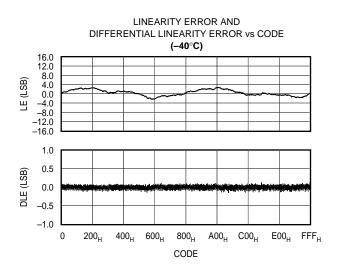
TYPICAL CHARACTERISTICS: $V_{DD} = +5V$ (Cont.)

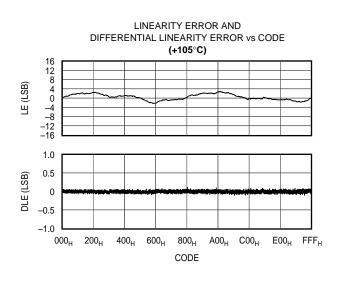
At $T_A = +25^{\circ}C$, $+V_{DD} = +5V$, unless otherwise noted.



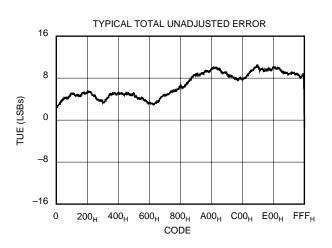
TYPICAL CHARACTERISTICS: $V_{DD} = +2.7V$

At $T_A = +25^{\circ}C$, $+V_{DD} = +2.7V$, unless otherwise noted.





LINEARITY ERROR AND DIFFERENTIAL LINEARITY ERROR vs CODE (+25°C) 16.0 12.0 8.0 4.0 0.0 -4.0 -8.0 LE (LSB) -12.0 -16.0 1.0 0.5 DLE (LSB) 0.0 -0.5 -1.0 200_H 400_H 600_H 800_H 0 A00_H C00_H E00_H FFF_H CODE

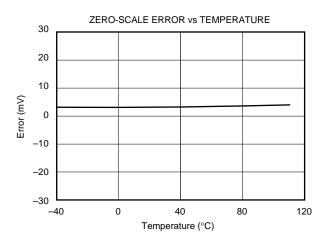


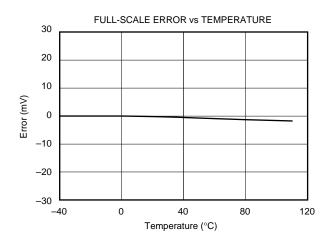


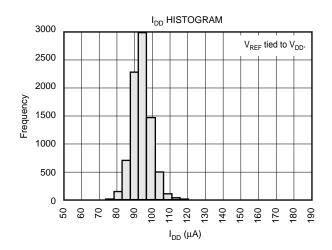


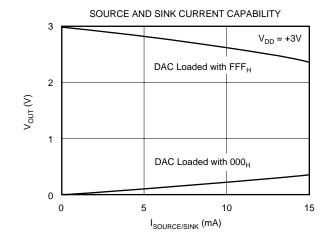
TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

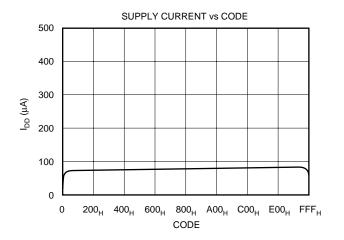
At $T_A = +25^{\circ}C$, $+V_{DD} = +2.7V$, unless otherwise noted.









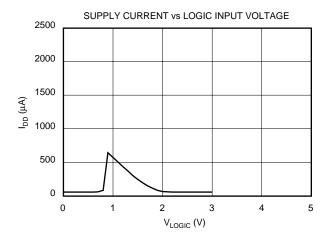


SUPPLY CURRENT vs TEMPERATURE -40 Temperature (°C)

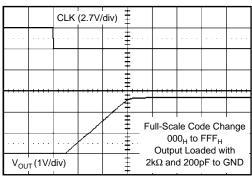


TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

At T_A = +25°C, +V_{DD} = +2.7V, unless otherwise noted.



FULL-SCALE SETTLING TIME



Time (1µs/div)

FULL-SCALE SETTLING TIME

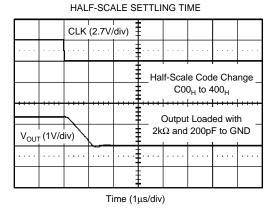
CLK	(2.7V	//div)							
_ V _{ou}	T (1V/0	div)			Fi		ale Coo F _H to	de Cha 000⊔	ange
			\sum			Outpu	ut Loa	ded wi	
• • • •			• • • •	\mathbf{X}	· · 2	ko an	a 200p	oF to C	

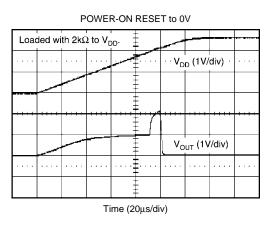
Time (1µs/div)

CLk	K (2.7\	//div)		 -			
-v _{ol}	 _{JT} (1V	/div) -	<i>د</i>	 	0 _H to (ut Loa	C00 _H ded wi	th _

HALF-SCALE SETTLING TIME

Time (1µs/div)

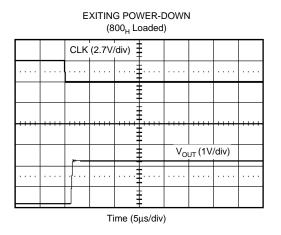


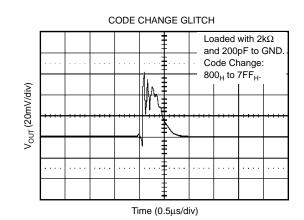




TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

At T_A = +25°C, +V_{DD} = +2.7V, unless otherwise noted.





THEORY OF OPERATION

DAC SECTION

The DAC7512 is fabricated using a CMOS process. The architecture consists of a string DAC followed by an output buffer amplifier. Since there is no reference input pin, the power supply (V_{DD}) acts as the reference. Figure 1 shows a block diagram of the DAC architecture.

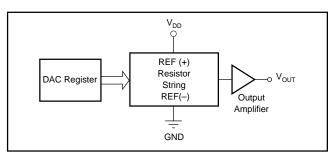


FIGURE 1. DAC7512 Architecture.

The input coding to the DAC7512 is straight binary, so the ideal output voltage is given by:

$$V_{OUT} = V_{DD} \bullet \frac{D}{4096}$$

where D = decimal equivalent of the binary code that is loaded to the DAC register; it can range from 0 to 4095.

RESISTOR STRING

The resistor string section is shown in Figure 2. It is simply a string of resistors, each of value R. The code loaded into the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier by closing one of the switches connecting the string to the amplifier. It is tested monotonic because it is a string of resistors.

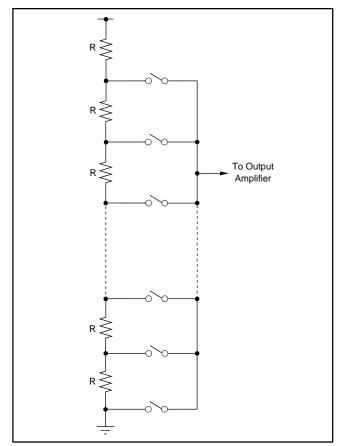


FIGURE 2. Resistor String.

OUTPUT AMPLIFIER

The output buffer amplifier is capable of generating rail-torail voltages on its output which gives an output range of 0V to V_{DD}. It is capable of driving a load of $2k\Omega$ in parallel with 1000pF to GND. The source and sink capabilities of the output amplifier can be seen in the typical characteristics. The slew rate is 1V/µs with a half-scale settling time of 8µs with the output unloaded.





SERIAL INTERFACE

The DAC7512 has a three-wire serial interface (\overline{SYNC} , SCLK, and D_{IN}), which is compatible with SPI, QSPI, and Microwire interface standards as well as most Digital Signal Processors (DSPs). See the Serial Write Operation timing diagram for an example of a typical write sequence.

The write sequence begins by bringing the \overline{SYNC} line LOW. Data from the D_{IN} line is clocked into the 16-bit shift register on the falling edge of SCLK. The serial clock frequency can be as high as 30MHz, making the DAC7512 compatible with high-speed DSPs. On the 16th falling edge of the serial clock, the last data bit is clocked in and the programmed function is executed (i.e., a change in DAC register contents and/or a change in the mode of operation).

At this point, the SYNC line may be kept LOW or brought HIGH. In either case, it must be brought HIGH for a minimum of 33ns before the next write sequence so that a falling edge of SYNC can initiate the next write sequence. Since the SYNC buffer draws more current when the SYNC signal is HIGH than it does when it is LOW, SYNC should be idled LOW between write sequences for lowest power operation of the part. As mentioned above, however, it must be brought HIGH again just before the next write sequence.

INPUT SHIFT REGISTER

The input shift register is 16 bits wide, as shown in Figure 3. The first two bits are "don't cares". The next two bits (PD1 and PD0) are control bits that control which mode of operation the part is in (normal mode or one of three power-down modes). There is a more complete description of the various modes in the Power-Down Modes section. The next 12 bits are the data bits. These are transferred to the DAC register on the 16th falling edge of SCLK.

SYNC INTERRUPT

In a normal write sequence, the SYNC line is kept LOW for at least 16 falling edges of SCLK and the DAC is updated on the 16th falling edge. However, if SYNC is brought HIGH before the 16th falling edge, this acts as an interrupt to the write sequence. The shift register is reset and the write sequence is seen as invalid. Neither an update of the DAC register contents or a change in the operating mode occurs, as shown in Figure 4.

POWER-ON RESET

The DAC7512 contains a power-on reset circuit that controls the output voltage during power-up. On power-up, the DAC register is filled with zeros and the output voltage is 0V; it remains there until a valid write sequence is made to the DAC. This is useful in applications where it is important to know the state of the output of the DAC while it is in the process of powering up.

POWER-DOWN MODES

The DAC7512 contains four separate modes of operation. These modes are programmable by setting two bits (PD1 and PD0) in the control register. Table I shows how the state of the bits corresponds to the mode of operation of the device.

DB13	DB12	OPERATING MODE
0	0	Normal Operation
		Power-Down Modes:
0	1	Output 1kΩ to GND
1	0	Output 100kΩ to GND
1	1	High-Z

TABLE I. Modes of Operation for the DAC7512.

When both bits are set to 0, the part works normally with its normal power consumption of 135μ A at 5V. However, for the three power-down modes, the supply current falls to 200nA at 5V (50nA at 3V). Not only does the supply current fall, but the output stage is also internally switched from the output of the amplifier to a resistor network of known values. This has the advantage that the output impedance of the part is known while the part is in power-down mode. There are three different options. The output is connected internally to GND through a 1k Ω resistor, a 100k Ω resistor, or it is left opencircuited (High-Z). See Figure 5 for the output stage.

DB15															DB0
х	x	PD1	PD0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
															,

FIGURE 3. Data Input Register.

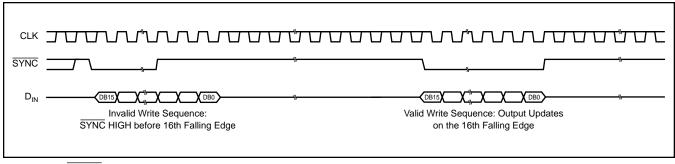


FIGURE 4. SYNC Interrupt Facility.



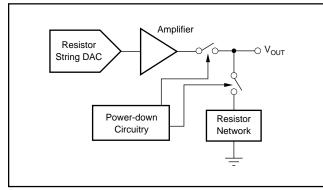


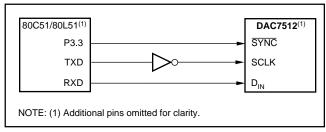
FIGURE 5. Output Stage During Power-Down.

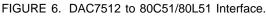
All linear circuitry is shut down when the power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The time to exit power-down is typically 2.5µs for $V_{DD} = 5V$ and 5µs for $V_{DD} = 3V$. See the Typical Characteristics for more information.

MICROPROCESSOR INTERFACING

DAC7512 TO 8051 INTERFACE

Figure 6 shows a serial interface between the DAC7512 and a typical 8051-type microcontroller. The setup for the interface is as follows: TXD of the 8051 drives SCLK of the DAC7512, while RXD drives the serial data line of the part. The SYNC signal is derived from a bit programmable pin on the port. In this case, port line P3.3 is used. When data is to be transmitted to the DAC7512, P3.3 is taken LOW. The 8051 transmits data only in 8-bit bytes; thus only eight falling clock edges occur in the transmit cycle. To load data to the DAC, P3.3 is left LOW after the first eight bits are transmitted, and a second write cycle is initiated to transmit the second byte of data. P3.3 is taken HIGH following the completion of this cycle. The 8051 outputs the serial data in a format which has the LSB first. The DAC7512 requires its data with the MSB as the first bit received. The 8051 transmit routine must therefore take this into account, and "mirror" the data as needed.





DAC7512 TO MICROWIRE[™] INTERFACE

Figure 7 shows an interface between the DAC7512 and any Microwire compatible device. Serial data is shifted out on the falling edge of the serial clock and is clocked into the DAC7512 on the rising edge of the SK signal.

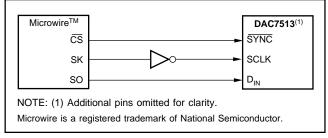
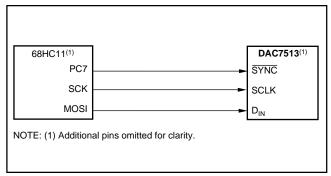
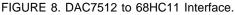


FIGURE 7. DAC7512 to Microwire Interface.

DAC7512 TO 68HC11 INTERFACE

Figure 8 shows a serial interface between the DAC7512 and the 68HC11 microcontroller. SCK of the 68HC11 drives the SCLK of the DAC7512, while the MOSI output drives the serial data line of the DAC. The SYNC signal is derived from a port line (PC7), similar to what was done for the 8051.





The 68HC11 should be configured so that its CPOL bit is a 0 and its CPHA bit is a 1. This configuration causes data appearing on the MOSI output is valid on the falling edge of SCK. When data is being transmitted to the DAC, the SYNC line is taken LOW (PC7). Serial data from the 68HC11 is transmitted in 8-bit bytes with only eight falling clock edges occurring in the transmit cycle. Data is transmitted MSB first. In order to load data to the DAC7512, PC7 is left LOW after the first eight bits are transferred, and a second serial write operation is performed to the DAC and PC7 is taken HIGH at the end of this procedure.

APPLICATIONS

USING REF02 AS A POWER SUPPLY FOR THE DAC7512

Due to the extremely low supply current required by the DAC7512, an alternative option is to use a REF02 +5V precision voltage reference to supply the required voltage to the part, see Figure 9. This is especially useful if the power supply is too noisy or if the system supply voltages are at some value other than 5V. The REF02 will output a steady supply voltage for the DAC7512. If the REF02 is used, the current it needs to supply to the DAC7512 is 135μ A. This is with no load on the output of the DAC. When the DAC output





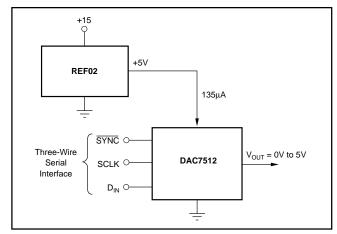


FIGURE 9. REF02 as Power Supply to DAC7512.

is loaded, the REF02 also needs to supply the current to the load. The total current required (with a $5k\Omega$ load on the DAC output) is:

 $135\mu A + (5V/5k\Omega) = 1.14mA$

The load regulation of the REF02 is typically 0.005%/mA, which results in an error of 285μ V for the 1.14mA current drawn from it. This corresponds to a 0.2LSB error.

BIPOLAR OPERATION USING THE DAC7512

The DAC7512 has been designed for single-supply operation but a bipolar output range is also possible using the circuit in Figure 10. The circuit shown will give an output voltage range of \pm 5V. Rail-to-rail operation at the amplifier output is achievable using an OPA340 as the output amplifier.

The output voltage for any input code can be calculated as follows:

$$V_{O} = \left[V \bullet \left(\frac{D}{4096} \right) \bullet \left(\frac{R_{1} + R_{2}}{R_{1}} \right) - V_{DD} \bullet \left(\frac{R_{2}}{R_{1}} \right) \right]$$

where D represents the input code in decimal (0 - 4095). With V_{DD} = 5V, R_1 = R_2 = 10k Ω :

$$V_{O} = \left(\frac{10 \bullet D}{4096}\right) - 5V$$

This is an output voltage range of $\pm 5V$ with 000_{H} corresponding to a -5V output and FFF_H corresponding to a +5V output.

LAYOUT

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies.

As the DAC7512 offers single-supply operation, it will often be used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult it will be to achieve good performance from the converter.

Due to the single ground pin of the DAC7512, all return currents, including digital and analog return currents, must flow through the GND pin. Ideally, GND would be connected directly to an analog ground plane. This plane would be separate from the ground connection for the digital components until they were connected at the power entry point of the system.

The power applied to V_{DD} should be well regulated and low noise. Switching power supplies and DC/DC converters will often have high-frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high-frequency spikes as their internal logic switches states. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. This is particularly true for the DAC7512, as the power supply is also the reference voltage for the DAC.

As with the GND connection, V_{DD} should be connected to a +5V power supply plane or trace that is separate from the connection for digital logic until they are connected at the power entry point. In addition, the 1µF to 10µF and 0.1µF bypass capacitors are strongly recommended. In some situations, additional bypassing may be required, such as a 100µF electrolytic capacitor or even a "Pi" filter made up of inductors and capacitors—all designed to essentially low-pass filter the +5V supply, removing the high-frequency noise.

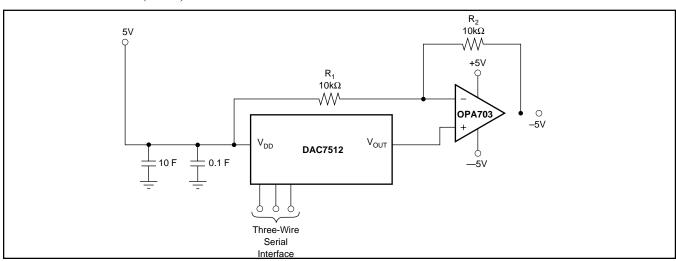
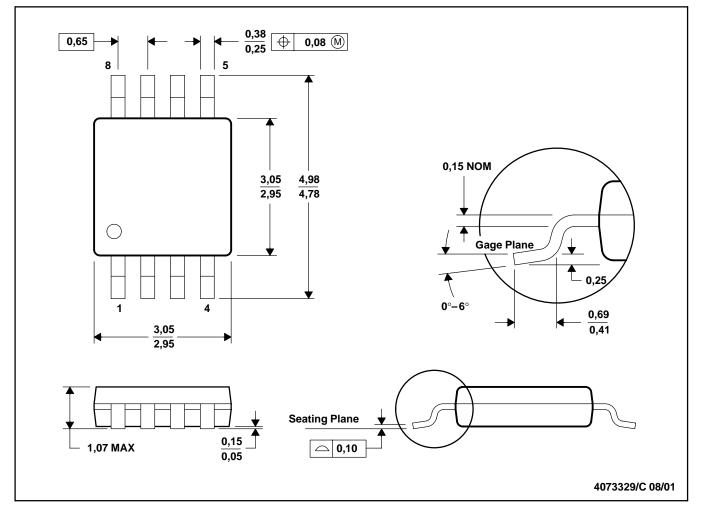


FIGURE 10. Bipolar Operation with the DAC7512.



DGK (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



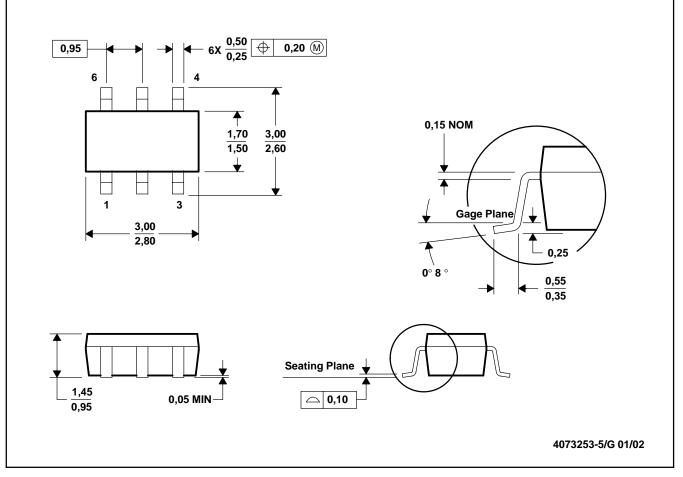
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187



DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Leads 1, 2, 3 may be wider than leads 4, 5, 6 for package orientation.





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
DAC7512E/250	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
DAC7512E/250G4	ACTIVE	MSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
DAC7512E/2K5	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
DAC7512E/2K5G4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
DAC7512N/250	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	Call TI	Level-2-260C-1 YEAR
DAC7512N/250G4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	Call TI	Level-2-260C-1 YEAR
DAC7512N/3K	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-2-260C-1 YEAR
DAC7512N/3KG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

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NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

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OBSOLETE: TI has discontinued the production of the device.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DBV (R-PDSO-G6)

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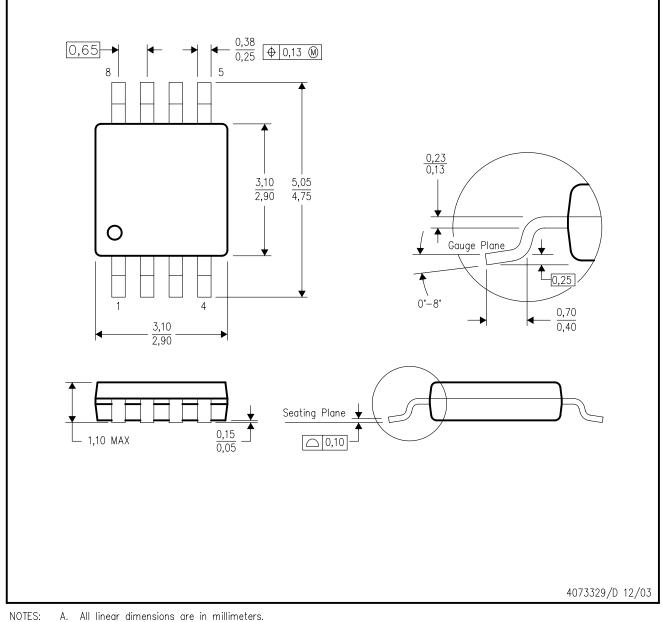


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- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- È. Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



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